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Panasonic

MOS FET FC8V22040L

FC8V22040L Gate Resistor installed Dual N-Channel MOS Type

For lithium-ion secondary battery protection circuit

- Features
- Low drain-source On-state Resistance: RDS(on)typ. = $10.5 \text{ m}\Omega(\text{VGS} = 4.5 \text{ V})$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 40

Basic Part Number : Dual Nch MOS 24V (Drain Common type)

Packaging

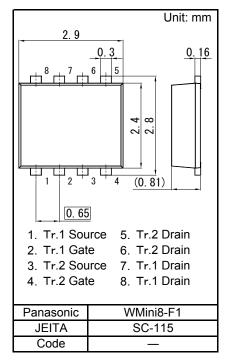
Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

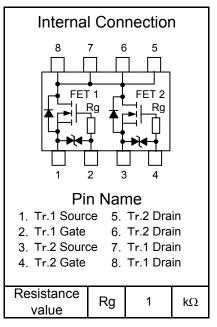
■ Absolute Maximum Ratings Ta = 25 °C Tr.1,Tr.2 Parameter Symbol Rating Unit Drain-source Voltage VDS 24 V FET1 Gate-source Voltage VGS ±12 V FET2 Drain Current ID 8 А Drain Current (Pulsed) IDp 48 A PD1 1.0 **Power Dissipation** 1.2 W PD2 0.4 PD3 Overall **Channel Temperature** °C Tch 150 **Operating Ambient Temperature** -40 to + 85 °C Topr Storage Temperature Range °C Tstg -55 to +150

Note) *1 Glass epoxy board: 25.4 mm × 25.4 mm × 0.8 mm Copper foil of the drain portion should have a area of 300 mm² or more PD absolute maximum rating without a heat shink: 400 mW

*2 t = 10 s

*3 Stand-alone (without the board)





Panasonic

MOS FET FC8V22040L

■ Electrical Characteristics Ta = 25°C ± 3°C Tr.1,Tr.2

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	VDSS	ID = 1.0 mA, VGS = 0	24			V
Drain-source cutoff current	IDSS	VDS = 24 V, VGS = 0			1.0	μA
Gate-source cutoff current	IGSS	$VGS = \pm 8.0 V, VDS = 0$			±10	μA
Gate threshold voltage	Vth	ID = 1.0 mA, VDS = 10 V	0.40	0.85	1.50	V
Drain-source ON resistance	RDS(ON)1	ID = 4.0 A, VGS = 4.5 V	7.0	10.5	15	mΩ
	RDS(ON)2	ID = 4.0 A, VGS = 4.0 V	7.2	11.0	16	mΩ
	RDS(ON)3	ID = 4.0 A, VGS = 3.1 V	7.5	12.0	18	mΩ
	RDS(ON)4	ID = 4.0 A, VGS = 2.5 V	8.0	13.5	20	mΩ
Turn-on delay time ^{*1}	td(on)	VDD = 10 V, VGS = 0 V to 4 V		0.6		μs
Rise time ^{*1}	tr	ID = 4.0 A		1.5		μs
Turn-off delay time ^{*1}	td(off)	VDD = 10 V, VGS = 4 V to 0 V		4.4		μs
Fall time ^{*1}	tf	ID = 4.0 A		2.8		μs
Source to Drain Diode Forward Voltage	VSD	IS = 4.0 A, VGS = 0 V		0.8	1.2	V

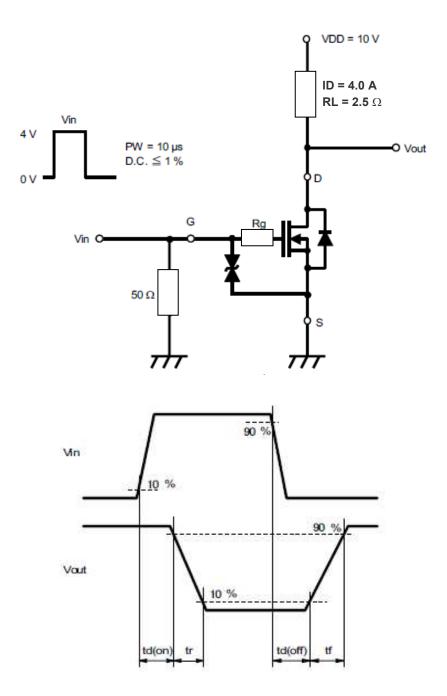
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

2. *1 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

Doc No. TT4-EA-13635 Revision. 3



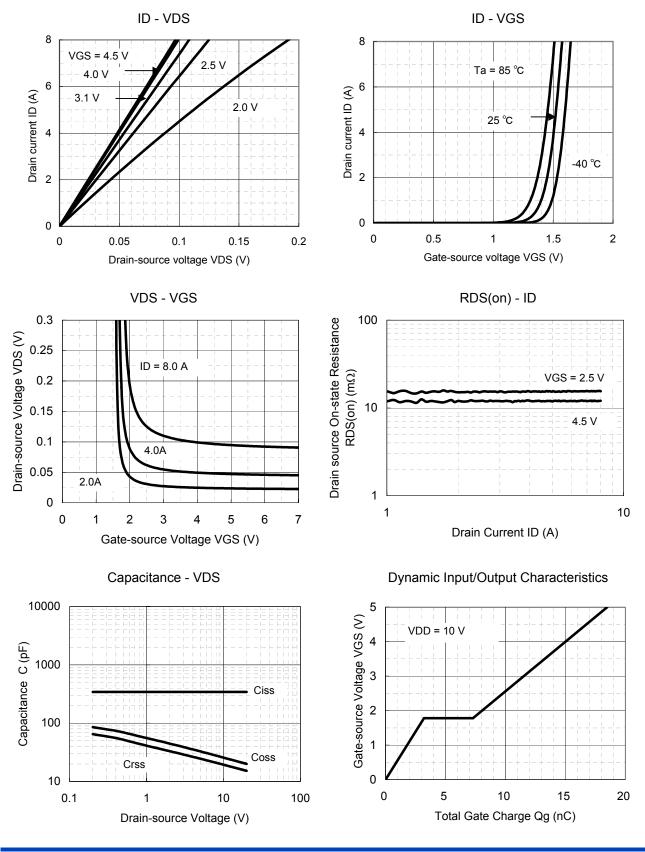
*1 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time







MOS FET FC8V22040L



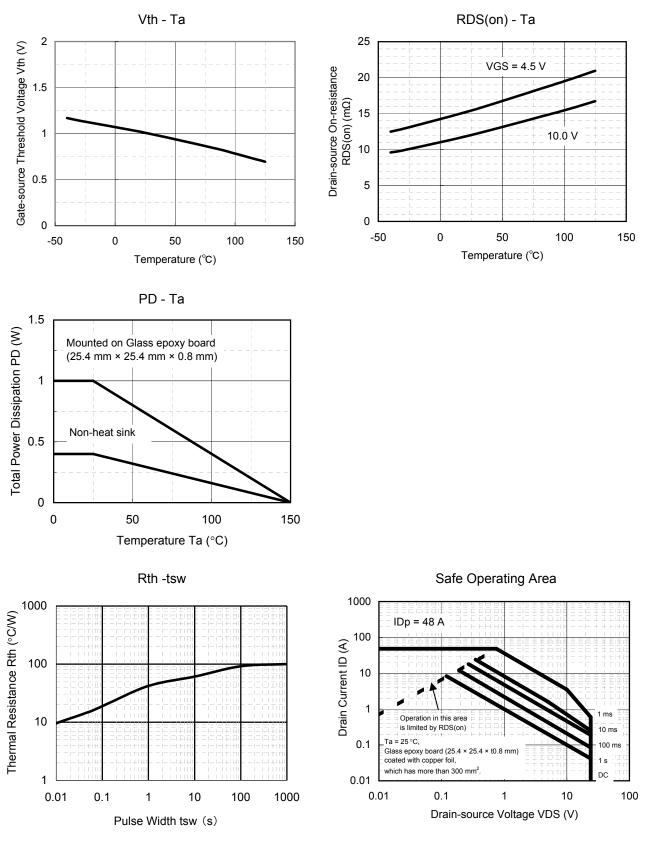
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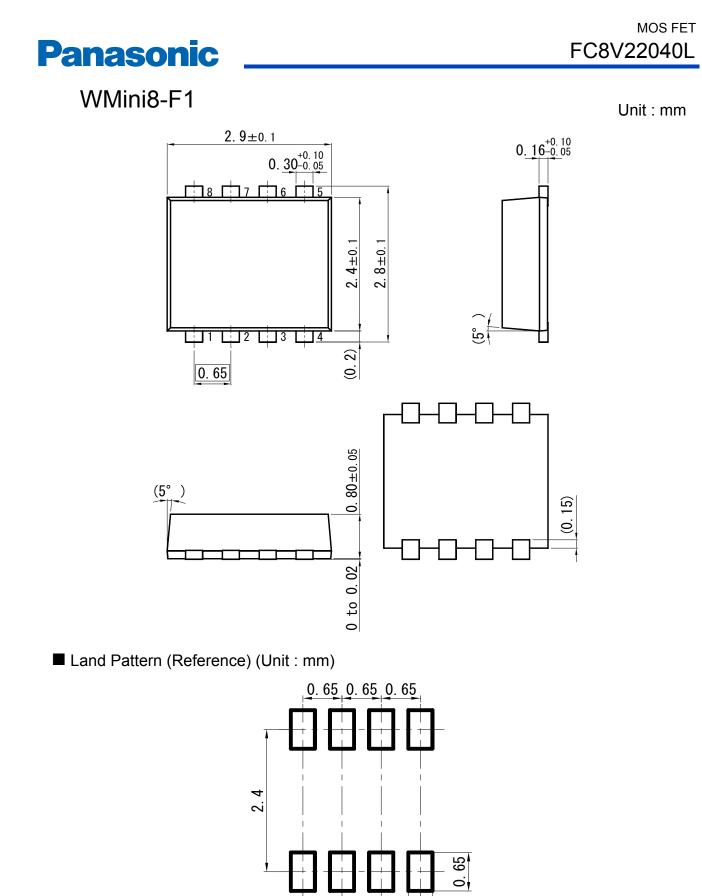




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